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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/537,274	03/29/2000	Larry Eugene Mosley	884.240US1	7167
21186	7590 04/16/2003			
SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.			EXAMINER	
	.O. BOX 2938 IINNEAPOLIS, MN 55402		THOMAS,	ERIC W
			ART UNIT	PAPER NUMBER
			2831	<u> </u>
			DATE MAILED: 04/16/2003	12

Please find below and/or attached an Office communication concerning this application or proceeding.

		NA SA
	Application No.	Applicant(s)
0.65	09/537,274	MOSLEY, LARRY EUGENE
Office Action Summary	Examiner	Art Unit
	Eric W Thomas	2831
The MAILING DATE of this communication Period for Reply	appears on the cover sheet v	vith the correspondence address
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CF after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, - If NO period for reply is specified above, the maximum statutory provided to reply within the set or extended period for reply will, by second and provided the reply received by the Office later than three months after the rearned patent term adjustment. See 37 CFR 1.704(b).	ON. R 1.136(a). In no event, however, may a n. a reply within the statutory minimum of thi eriod will apply and will expire SIX (6) MO statute, cause the application to become A	reply be timely filed rly (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).
1) Responsive to communication(s) filed on	<u>21 January 2003</u> .	
2a)⊠ This action is FINAL . 2b)□	This action is non-final.	
Since this application is in condition for al closed in accordance with the practice un Disposition of Claims		
4) Claim(s) 2-7 and 9-21 is/are pending in the	e application.	
4a) Of the above claim(s) is/are with	ndrawn from consideration.	
5)⊠ Claim(s) <u>6,7 and 9-18</u> is/are allowed.		
6)⊠ Claim(s) <u>2-5,19 and 21</u> is/are rejected.		
7) Claim(s) <u>20</u> is/are objected to.		
8) Claim(s) are subject to restriction a	nd/or election requirement.	
Application Papers	•	
9)☐ The specification is objected to by the Exar	miner.	
10) The drawing(s) filed on is/are: a) ☐ a	accepted or b) Objected to by	the Examiner.
Applicant may not request that any objection		
11) \boxtimes The proposed drawing correction filed on $\underline{2}$		ved b) disapproved by the Examiner.
If approved, corrected drawings are required	• •	
12) The oath or declaration is objected to by the	e Examiner.	
Priority under 35 U.S.C. §§ 119 and 120		
13) Acknowledgment is made of a claim for for	reign priority under 35 U.S.C.	§ 119(a)-(d) or (f).
a) ☐ All b) ☐ Some * c) ☐ None of:		
 Certified copies of the priority document 	nents have been received.	
Certified copies of the priority document	nents have been received in a	Application No
 3. Copies of the certified copies of the application from the Internationa * See the attached detailed Office action for a 	Il Bureau (PCT Rule 17.2(a)).	-
14) Acknowledgment is made of a claim for dom	·	
a) ☐ The translation of the foreign language 15)☐ Acknowledgment is made of a claim for don	e provisional application has l	peen received.
Attachment(s)	needo priority under 50 0.5.0	. 33 120 and/01 121.
Notice of References Cited (PTO-892)	4) Interview	Summary (PTO-413) Paper No(s)
Notice of Natisperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No.	5) Notice o	Informal Patent Application (PTO-152)

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Introduction:

The examiner acknowledges, as recommended in the M.P.E.P., the applicant's submission of the amendment dated 1/21/03. At this point claims 2, 4, 6, and 7 have been amended; and claims 1 and 8 have been cancelled. Claims 2-7, 9-21 are pending in the instant application.

Claim Rejections - 35 USC § 112

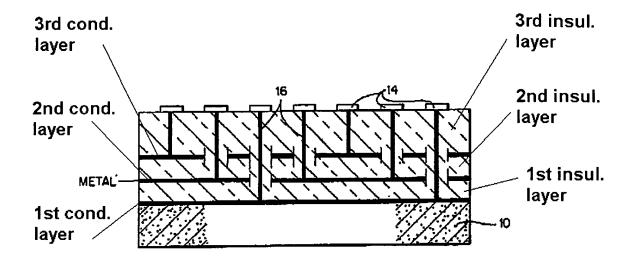
- The following is a quotation of the second paragraph of 35 U.S.C. 112:
 The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 2. Claim 21 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 21 depends on a cancelled claim. The examiner examined this claim as if it depended on claim 2.

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 4-5, 19, are rejected under 35 U.S.C. 103(a) as being unpatentable over IBM Technical disclosure bulletin (Cross-reference 0018-8689-20-8-3117 Referred as '3117).

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'3117 discloses a multi layer integrated circuit capacitor comprising: a substrate (10); a first conductive layer located over and contacting the substrate (see above);

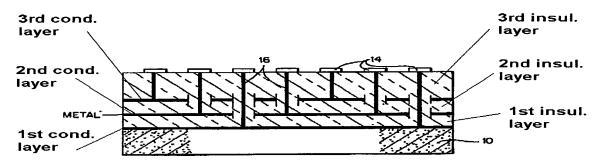
a first insulator layer located over and contacting the first conductive layer, the first insulator layer not contacting the substrate; a second conductive layer located over the first insulator layer; a second insulator layer located over the second conductive layer; a third conductive layer located over the second insulator layer; a third insulator layer located over the third conductor layer; and a plurality of conductive vias (16) downwardly extending through the third insulator layer to provide electrical interconnection to the first, second and third conductive layers.

'3117 discloses the claimed invention except for the insulator layers are formed from a BaSrTiO3 material. It is well known in the capacitor art to form insulating layers from a BaSrTiO3 material (excellent dielectric properties). It

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would have been obvious to one having ordinary skill in the art at the time the invention was made to form the dielectric from a BaSrTiO3, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

Regarding claim 5, '3117 discloses the claimed invention for the conductive layers are formed from copper. It is well know in the capacitor art to form conductive layers (electrodes) from a copper material (excellent conductive properties). It would have been obvious to one having ordinary skill in the art at the time the invention was made to form the conductive layers from a copper material, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.



Regarding claim 19, '3117 discloses a multi layer integrated circuit capacitor comprising: a substrate (10); a first conductive layer located over and contacting the substrate (see above); a first insulator layer located over and contacting the first conductive layer, the first insulator layer not contacting the substrate; a second conductive layer located over the first insulator layer; a

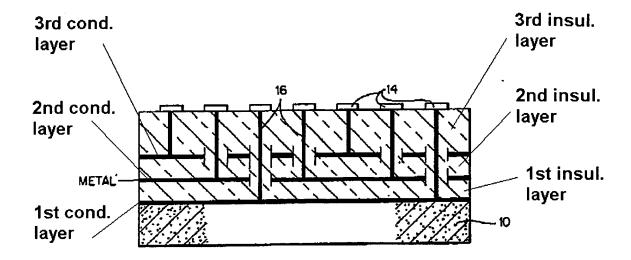
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second insulator layer located over the second conductive layer; a third conductive layer located over the second insulator layer; a third insulator layer located over the third conductor layer; and a plurality of conductive vias (16) downwardly extending through the third insulator layer to provide electrical interconnection to the first, second and third conductive layers.

'3117 discloses the claimed invention except for the plurality of vias extending through the substrate to provide electrical interconnection to both a top surface and a bottom surface of the integrated circuit capacitor. It is well known in the capacitor art to extend vias through a substrate to provide electrical interconnections to both sides of the capacitive element. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to extend the vias of '3117 through the substrate to provide electrical interconnections to both sides of the capacitor, since such a modification would decrease the space needed in the electrical system.

3. Claims 2-3, and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over IBM Technical disclosure bulletin (Cross-reference 0018-8689-20-8-3117 – Referred as '3117) in view of Herrell (US 6,191,479).

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'3117 discloses a multi layer integrated circuit capacitor comprising: a substrate (10); a first conductive layer located over and contacting the substrate (see above);

a first insulator layer located over and contacting the first conductive layer, the first insulator layer not contacting the substrate; a second conductive layer located over the first insulator layer; a second insulator layer located over the second conductive layer; a third conductive layer located over the second insulator layer; a third insulator layer located over the third conductor layer; and a plurality of conductive vias (16) downwardly extending through the third insulator layer to provide electrical interconnection to the first, second and third conductive layers.

'3117 disclose the claimed invention except for a plurality of controlled collapse chip connection (C4) lands fabricated on and contacting the third insulator layer and in electrical contact with the plurality of conductive vias. '3117

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illustrates voltage supply pads formed on and contacting the third insulator layer and in electrical contact with the plurality of conductive vias. The capacitor is connected to a chip by short metal lines (see fig. 2).

Herrell teaches the use of C4 lands that electrically contacts vias in the capacitor art. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to modify the capacitor of '3117 using the C4 lands as taught by Herrell, since such a modification would decrease the space used in the electrical system by placing the capacitor directly onto the chip.

Regarding claim 3, '3117 disclose the claimed invention except for C4 lands fabricated in staggered columns in a plan view. '3117 illustrates a column of voltage supply pads arranged on a capacitor. Herrell illustrates multiple C4 lands fabricated in staggered columns in a plan view. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to form multiple C4 lands which is fabricated in staggered columns in a plan view, since such a modification would allow additional connections to the capacitor of '3117.

Regarding claim 21, '3117 discloses the claimed invention for the conductive layers are formed from copper. It is well know in the capacitor art to form conductive layers (electrodes) from a copper material (excellent conductive properties). It would have been obvious to one having ordinary skill in the art at the time the invention was made to form the conductive layers from a copper material, since it has been held to be within the general skill of a worker in the art

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to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

'3117 discloses the claimed invention except for the insulator layers are formed from a BaSrTiO3 material. It is well known in the capacitor art to form insulating layers from a BaSrTiO3 material (excellent dielectric properties). It would have been obvious to one having ordinary skill in the art at the time the invention was made to form the dielectric from a BaSrTiO3, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

Allowable Subject Matter

- 4. Claims 6-7, 9-18 are allowed.
- 5. Claim 20 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Response to Arguments

6. Applicant's arguments, see page 4, filed 1/21/03, with respect to claims 11 and 13 have been fully considered and are persuasive. The rejection of claims 11 and 13 has been withdrawn.

Official Notice

A) "Applicant objects to the official notice (with regard to the materials used for the insulator and electrode) using a single reference and respectfully

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request that additional references be cited in support of this position." The examiner addressed this objection in the final action dated 11/7/01 (see below).

Strontium Barium Titanate (SBT) is a well-known dielectric material used in the capacitor art. SBT is known for its high dielectric constant. See US 5,679,980; 5,793,057; 5,811,851; 5,781,404; 5,729,054; & 5,696,018.

Copper is a well-known electrode material. Copper has excellent electro-conductivity. See 5,910,881; 5,471,363; 5,512,353 5,093,757; 5,159,524; 5,117,326; 5,107,394; & 6,101,693.

B) "Applicant objects to the official notice (with regard to the vias extending through the substrate to provide electrical interconnects on the bottom side of the capacitor) using a single reference and respectfully request that additional references be cited in support of this position."

Fig. 6 of Kuroda et al. (US 6,351,369 and 6,370,010) illustrate vias that extend through a substrate to provide interconnects to the capacitor.

'3117 in view of Herrell

7. In response to applicant's arguments against the references individually, one cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); *In re Merck & Co.*, 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986).

Conclusion

8. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**.

See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Eric W Thomas whose telephone number is (703) 305-0878. The examiner can normally be reached on Mon & Sat 9:00AM - 9:30PM; Tues-Fri 5:30PM-10:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Dean Reichard can be reached on 703-308-3682. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9318 for regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800